

# Synthesis of the uniform hollow spherical $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$ phosphors via an *h*-BN protective method



Jia-Ye Tang, Hao Zhong, Lu-Yuan Hao, Xin Xu\*

Chinese Academy of Science Key Laboratory of Materials for Energy Conversion, Department of Materials Science and Engineering, University of Science and Technology of China, Hefei Anhui, People's Republic of China

## ARTICLE INFO

### Article history:

Received 21 May 2013

Received in revised form 8 July 2013

Accepted 29 July 2013

Available online 4 September 2013

### Keywords:

Sol-gel growth

Optical properties

Core-shell structure

White light-emitting diodes

## ABSTRACT

The uniform hollow spherical  $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$  green emitting phosphors have been successfully synthesized using hollow silica spheres as templates by an *h*-BN protective method. The scanning electron microscopy (SEM) and transmission electron microscopy (TEM) results directly confirmed the existence of the hollow spherical structure with a narrow size distribution and a shell thickness of 15–25 nm. The *h*-BN protective film, observed by high resolution TEM, plays an important role in the formation of the hollow spherical morphology and the improvement of photoluminescence properties. Comparing with the  $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$  micron-phosphor prepared by the traditional solid state reaction method, the hollow spherical phosphor with nano-sized grains exhibits stronger green emission under ultraviolet–blue light excitation. This could be attributed to the elimination of surface defects by the *h*-BN coating. This research gives an economic and convenient way to synthesize uniform spherical phosphors with high quantum efficiency.

© 2013 Elsevier B.V. All rights reserved.

## 1. Introduction

White light-emitting diodes (WLEDs) have attracted much more attention as light sources for new generation luminescent and displaying devices due to their high quantum efficiency, low energy consumption, long life time and environmental friendly.[1–4] There are many methods to generate white light, however, the combination of LED chips with phosphors is considered to be the most convenient and economic way [5,6].

The phosphor powders should be dispersed in the resin and dropped on the surface of the LED chip to obtain a uniform phosphor layer, so their morphology and particle size distribution play important roles in improving quality of the WLEDs. Spherical phosphors with a narrow size distribution are getting much more attentions in recent decades [7–11]. However, It is very difficult to achieve that, because most of the potential phosphors, such as silicate and oxynitride, are often synthesized at high temperature with long calcination time, resulting in a significant agglomeration and broad size distribution of the particles [12,13]. A lot of attempts have been made to prepare small phosphor particles with narrow size distribution. Some phosphors are successfully fabricated, such as  $\text{SiO}_2:\text{YBO}_3:\text{Eu}^{3+}$  [14], BHA (or BAM) [15] and hollow  $\text{Gd}_2\text{O}_3:\text{Ln}$  ( $\text{Ln} = \text{Eu}^{3+}, \text{Sm}^{3+}$ ) [16] phosphors. We have successfully

invented an *h*-BN protective method to synthesize the core-shell structured spherical oxynitride phosphors at relative low temperature, such as  $\text{SrSi}_2\text{O}_2\text{N}_2:\text{Eu}^{2+}$  and  $\text{Sr}_2\text{Si}_5\text{N}_8:\text{Eu}^{2+}$  phosphors [17,18].

Due to their unique structural, optical, and surface properties, hollow inorganic spheres have many potential applications, such as catalysis, encapsulation, coatings and drug delivery. For phosphor application, the hollow structure could reduce the usage of the raw materials and eliminate the cost in commercial production, because only the surface of phosphor has contribution to the photoluminescence. Many efforts have also been made towards the fabrication of the hollow spherical phosphors [19–22], however, there is still a challenge to find a simple method.

In this letter, we success in synthesizing hollow  $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$  spherical phosphors by the *h*-BN protective method using hollow  $\text{SiO}_2$  spheres as templates. The as-received phosphors show an intense green emission under UV excitation.

## 2. Experimental

### 2.1. Materials

All the as-received materials are directly used without further purification, which contains  $\text{Sr}(\text{NO}_3)_2$  (Sinopharm Chemical Reagent Co. Ltd, Shanghai, China, >99.99%),  $\text{Eu}_2\text{O}_3$  (99.99%), ammonium hydroxide ( $\text{NH}_4\text{OH}$ , 25–28%) tetraethyl orthosilicate (TEOS, 99.99%), dilute nitric acid ( $\text{HNO}_3$ , Analytical reagent, AR), styrene ( $\text{C}_6\text{H}_5\text{CH}=\text{CH}_2$ , AR), polyvinylpyrrolidone K-30 (PVP K-30,

\* Corresponding author. Tel.: +86 551 63600824(o), +86 13865967499(m); fax: +86 551 63601592.

E-mail address: [xuxin@ustc.edu.cn](mailto:xuxin@ustc.edu.cn) (X. Xu).

99.99%), ethanol ( $C_2H_5OH$ , AR), azo dibutyl cyanide (AIBN, AR), citric acid ( $C_6H_8O_7$ , AR),  $H_3BO_3$  (AR) and polyethylene glycol (PEG, molecular weight = 10,000, AR) and distilled water.

## 2.2. Preparation of polystyrene (PS) microspheres

The micrometer PS particles with an average diameter of  $\sim 800$  nm were synthesized by the polycondensation of styrene ( $C_6H_5CH=CH_2$ ) via the sol–gel procedure [23]. In a typical procedure, 2.0 g PVP K-30 were added to a 330 ml water–ethanol ( $V/V = 1:10$ ) solution and stirred at room temperature to make the PVP K-30 completely dissolved in the solution, then 0.3 g AIBN was dissolved in the mixture solution, at last, 33 ml styrene were dissolved in the solution and stirred at 70 °C oil bath with reflux condensation process under  $N_2$  flow for 24 h. The resulting PS spheres were centrifugally separated from the suspension, washed three times with ethanol and dried at 60 °C for 12 h.

## 2.3. Coating of PS spheres with a $SiO_2$ shell

The PS spheres were successfully coated with  $SiO_2$  layers on the surface by the basic hydrolysis and condensation of TEOS through the well-know stöber method [24,25]. First, 0.5 obtained PS spheres were added in 200 ml ethanol solution and ultrasonic dispersed for 15 min, then 3 ml TEOS and 8 ml  $NH_4OH$  were added in the suspension solution and stirred for another 12 h at room temperature, resulting in the formation of the  $PS@SiO_2$  core–shell structured particles. The  $PS@SiO_2$  particles were centrifugally separated from the suspension, washed three times with ethanol and dried at 100 °C.

## 2.4. Fabrication of hollow spherical $SiO_2@SrCO_3:Eu^{3+}$ core–shell structured precursor particles

The  $Sr^{2+}$  and  $Eu^{3+}$  ions are coated on the surface of the core–shell structured  $PS@SiO_2$  particles via the famous Pechini-type sol–gel method [26–28]. First, the  $Sr(NO_3)_2$  and  $Eu_2O_3$  powders were dissolved in dilute  $HNO_3$  solution to form the  $Sr^{2+}$  and  $Eu^{3+}$  ion solution. The molar ratio of  $Eu^{3+}$  to  $Sr^{2+}$  was set to 0.02, which is consistent with the optimum concentration of the  $Sr_2SiO_4:Eu^{2+}$  phosphors [29,30]. Then stoichiometric amount of  $Sr(NO_3)_2$  and  $Eu(NO_3)_3$  solution were dissolved in a water–ethanol ( $V/V = 1:4$ ) solution with citric acid as chelating agent for metal ions, and the molar ratio of metal ions to citric acid was 1:2. Then the polyethylene glycol (PEG, molecular weight = 10,000) was added with a concentration of 0.10 g/mL. The solution was stirred for 4 h at room temperature. At last, the particles were separated by centrifugation and washed three times with ethanol solution and dried at 100 °C. The obtained  $PS@SiO_2@SrCO_3:Eu^{3+}$  core–shell structured particles (For convenience, the metal compounds of Sr and Eu elements on the surface of  $PS@SiO_2$  particles are named with  $@SrCO_3:Eu^{3+}$ .) were annealed at 500 °C for 2 h in air to remove the PS cores and make the outer  $SrCO_3:Eu^{3+}$  layer adhere tightly to the inner spherical  $SiO_2$  cores.

## 2.5. Synthesis of the hollow spherical $Sr_2SiO_4:Eu^{2+}$ phosphors via gas reduction and nitridation method

The  $H_3BO_3$  layers were coated on the spherical hollow spheres using the wet chemical method, according to its different solubilities in aqueous solution at different temperatures. The as-prepared hollow spherical and an appropriate amount of  $H_3BO_3$  powders are mixed in distilled water solutions at a relative high temperature. After the  $H_3BO_3$  powders are completely dissolved in distilled water, the solution was naturally cooled to room temperature to

make the  $H_3BO_3$  powders coat on the surface of the hollow spherical  $SiO_2@SrCO_3:Eu^{2+}$  precursor particles.

The obtained hollow spherical  $SiO_2@SrCO_3:Eu^{2+}@H_3BO_3$  precursor particles were placed in a boron nitride (BN) boat, and horizontally loaded into the alumina ( $Al_2O_3$ ) tubular furnace with an inner diameter of 50 mm. The temperature was heated to 1000 °C in 3 h and maintained at 1000 °C for another 2 h, then increased to 1400 °C and kept at the temperature for 8 h in flowing  $N_2/NH_3$  atmosphere. After the heating process, the sample were slowly cooled to 800 °C, then naturally cooled to room temperature. The detailed schematic fabrication procedure of the hollow spherical  $Sr_2SiO_4:Eu^{2+}$  phosphors are shown in Scheme 1. For comparison, the pure  $Sr_2SiO_4:Eu^{2+}$  phosphors were also synthesized by a traditional solid state reaction method at the same condition expect for the  $H_3BO_3$  coating powders.

## 2.6. Characterization

All the powder products were well grounded and identified by X-ray powder diffraction (XRD, PW 1700, Philips, Netherlands) using  $Cu K\alpha_1$  radiation ( $\lambda = 1.54056 \text{ \AA}$ ) at 40 kV and 100 mA with a graphite monochromator. The powders were placed in a silica chip vertically in the machines with a  $2\theta/\theta$  scan axis. The data were collected using a step size of  $0.0167^\circ$  in the  $2\theta$  range from  $10^\circ$  to  $70^\circ$  at a scanning speed of  $2^\circ/\text{min}$ .

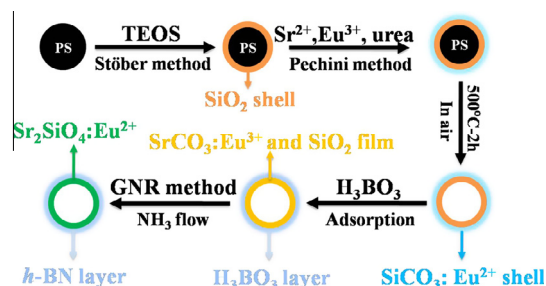
The morphology of the core–shell samples was investigated using a scanning electron microscope (SEM), which is equipped with a back scattered electron image (BSEI) (JEOL-6390LA, JEOL, Japan). The Energy Dispersive X-ray Spectrometer EDS and inductively coupled plasma atomic emission spectrometer (ICP-AES) (Optima 7300DV, Perkin Elmer Corporation, USA) were used to analysis the elements of the core–shell structure. The core–shell structure was investigated using the high resolution transition electron microscopy (HR-TEM) (JEOL-2010, JEOL, Japan).

The photoluminescence spectra were measured at room temperature by a fluorescent spectrophotometer (F-4600, Hitachi Ltd., Japan) with a 200 W Xe-lamp as an excitation source. The emission spectrum was corrected for the spectral response of a monochromator and Hamamatsu R928P photomultiplier tube (Hamamatsu Photonics K.K., Hamamatsu, Japan) by a light diffuser and tungsten lamp (Noma Electric Corp., NY; 10 V, 4 A). The excitation spectrum was also corrected for the spectral distribution of the xenon lamp intensity by measuring Rhodamine-B as references.

## 3. Results and discussion

### 3.1. Phase, structure and elementary composition of the hollow spherical $Sr_2SiO_4:Eu^{2+}$ phosphor

Fig. 1 shows the XRD pattern of the as-received spherical hollow  $Sr_2SiO_4:Eu^{2+}$  phosphor and the JCPDS 76-1494 card for  $Sr_2SiO_4$  as



Scheme 1. The schematic fabrication processes of the hollow spherical  $Sr_2SiO_4:Eu^{2+}$  phosphors.

Download English Version:

<https://daneshyari.com/en/article/1494962>

Download Persian Version:

<https://daneshyari.com/article/1494962>

[Daneshyari.com](https://daneshyari.com)